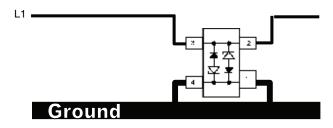
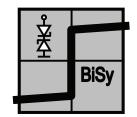


BiSy-mode (1-line Bidirectional Symmetrical protection mode)

The **GCDA15C-1** is a 1-line **Bi**directional, **Sy**mmetrical (**BiSy**) protection device. Two avalanche diodes each in series with a PN-Diode providing a very low capacitance. Due to its symmetry the electrical performance is also symmetrical. For an optimal ESD-protection the line inductance of the protection path (current path from the data line (L1) through the protection device to ground) has to be minimized. For this the data line which has to be protected should be led trough the **GCDA15C-1** - one pin (e.g. Pin 3) "in" and the other pin (e.g. Pin 2) "out". The Ground pins (e.g.Pin 1 and 4) should be connected to ground on the shortest and broadest way to keep the inductance as low as possible!





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Electrical Characteristics

BiSy mode (between Pin 2 + 3 and 1 + 4)

Ratings at 25 °C, ambient temperature unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур.	Max	Unit
Reverse Working Voltage	at I _R = 0.1 μA	V_{RWM}	15	16.5		V
Reverse Current	at V _R = V _{RWM} = 15 V	I _R		< 0.001	0.1	μΑ
Reverse Clamping Voltage	at I _{PP} = 1 A	V _C		18.5	21	V
Reverse Clamping Voltage	at I _{PP} = I _{PPM} = 10 A	V _C		26	30	V
Reverse Break down Voltage	at I _R = 1 mA	V _R	16	17		V
Capacitance	at $V_R = 0 V$, $f = 1 MHz$	C _D		1.5	2	pF
Capacitance	at V _R = 15 V, f = 1 MHz	C _D		1.3		pF
ESD-Clamping voltage peak	at ± 8 kV ESD-pulse acc. IEC 61000-4-2	V _{CESD}		130		V
Protection paths	number of lines which can be protected	N _{lines}		1		lines

Typical Characteristics

Ratings at 25 °C, ambient temperature unless otherwise specified

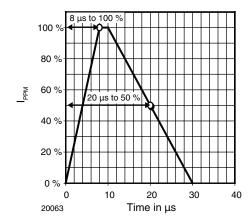


Figure 1. 8/20 µs Peak Pulse Current wave form acc. IEC 61000-4-5

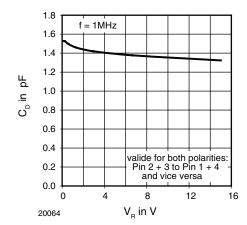


Figure 2. Typical Capacitance C_D vs. Reverse Voltage V_R

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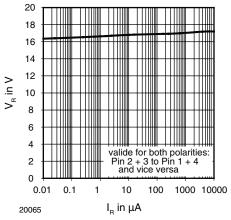


Figure 3. Typical Reverse Voltage V_R vs. Reverse Current I_R

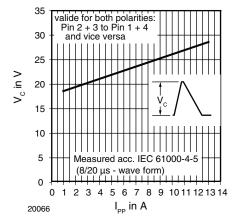


Figure 4. Typical peak clamping voltage V_{C} vs. peak pulse current I_{PP}

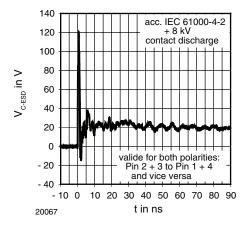


Figure 5. Typical Clamping performance at 8 kV contact discharge (acc. IEC 61000-4-2)

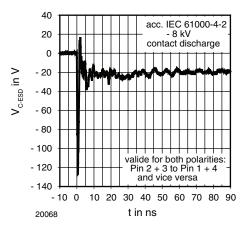


Figure 6. Typical Clamping performance at 8 kV contact discharge (acc. IEC 61000-4-2)

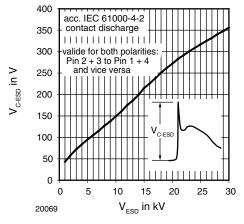
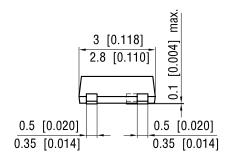
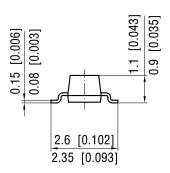


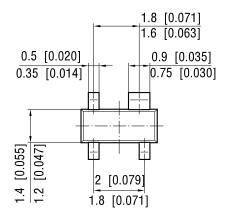
Figure 7. Typical peak clamping voltage at ESD contact discharge (acc. IEC 61000-4-2)

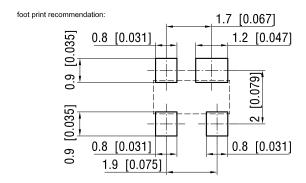
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Package Dimensions in mm (Inches) SOT143









Rev. 5 - Date: 25.January.2005 Document no.: 6.541-5015.01-4

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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